

IN THE CLAIMS:

Please amend the claims to read as follows:

Claim 1 (Currently Amended): A liquid crystal display device, comprising:

a transparent insulating substrate;

a gate line and a gate electrode on the transparent insulating substrate;

a gate insulating film, an active layer, an ohmic contact layer, source and drain electrodes, and a data line on the transparent insulating substrate;

a passivation film formed on the transparent insulating substrate including the source and drain electrodes and the data line;

a compensation film formed in a pixel region to contact the passivation film, the compensation film compensates for phase variations of light; and

a pixel electrode formed on at least the compensation film,

wherein the pixel electrode overlaps the data line and the compensation film is only located under the pixel electrode.

Claim 2 (Original): The device according to claim 1, wherein the pixel electrode includes ITO.

Claim 3 (Currently Amended): A method of fabricating a liquid crystal display device, comprising:

forming a gate line and a gate electrode on a transparent insulating substrate;

forming a gate insulating film, an active layer, an ohmic contact layer, source and drain electrodes, and a data line on the transparent insulating substrate;

forming a passivation film on the transparent insulating substrate including the source and drain electrodes and the gate line;

forming a compensation film in a pixel region to contact at least the passivation film, the compensation film compensates for phase variations of light; and

forming a pixel electrode on the compensation film,

wherein the pixel electrode overlaps the data line and the compensation film is only located under the pixel electrode.

Claim 4 (Original): The method according to claim 3, wherein the pixel electrode includes an ITO metal film.

Claims 5-11 (Canceled).

Claim 12 (Currently Amended): A liquid crystal display device, comprising:

a thin film transistor substrate;

a pixel electrode formed on the thin film transistor substrate;

a color filter substrate including a black matrix;

a common electrode formed on the color filter substrate;

a liquid crystal material formed between the thin film transistor substrate and the color filter substrate; and

a compensation film at least disposed between the pixel electrode and the thin film transistor substrate to contact the pixel electrode within a pixel region,

wherein the compensation film compensates for phase variations of light transmitted through the liquid crystal material and is only located under the pixel electrode.

Claim 13 (Previously Presented): The device according to claim 12, further comprising an overcoat film formed between the compensation film and a color filter film on the color filter substrate.

Claim 14 (Original): The device according to claim 13, wherein the overcoat film is formed between red, green, and blue color filter layers of the color filter film.

Claim 15 (Previously Presented): The device according to claim 14, wherein the overcoat film contacts the black matrix formed between the red, green, and blue color filter layers.

Claim 16 (Original): The device according to claim 14, wherein the overcoat film contacts the red, green, and blue color filter layers.

Claims 17-21 (Canceled).

Claim 22 (New): The device according to claim 1, wherein the compensation film is formed with a single uniform layer.

Claim 23 (New): The method according to claim 3, wherein the compensation film is formed with a single uniform layer.

Claim 24 (New): The device according to claim 12, wherein the compensation film is formed with a single uniform layer.